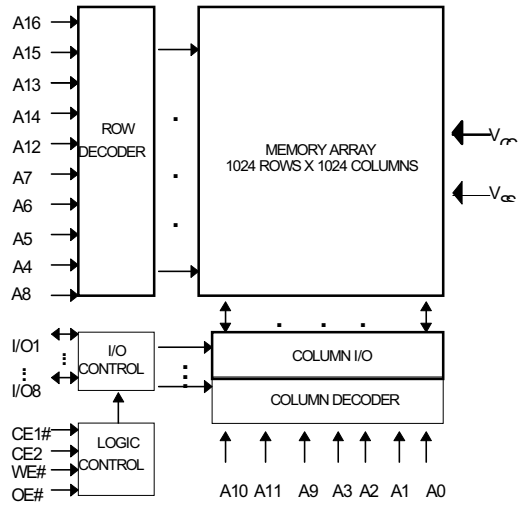
FEATURES

- Power Supply range 3.1V to 3.6V
- Fast access time : 12/15 ns (max.)
- Low operating power consumption : 60 mA (typical)
- All inputs and outputs TTL compatible
- Fully static operation
- Three state outputs
- Package : 32-pin 300 mil skinny PDIP
  32-pin 300 mil SOJ
  32-pin 8 x 20mm TSOP-1
  32-pin 8 x 13.4mm STSOP

FUNCTIONAL BLOCK DIAGRAM



PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0 - A16	Address Inputs
I/O1 - I/O8	Data Inputs/Outputs
CE#1,CE2#	Chip enable 1,2 Inputs
WE#	Write Enable Input
OE#	Output Enable Input
V_{CC}	Power Supply
V_{SS}	Ground
NC	No Connection

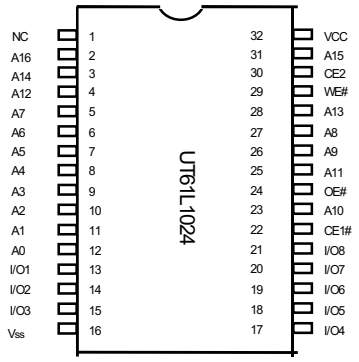
GENERAL DESCRIPTION

The UT61L1024 is a 1,048,576-bit high-speed CMOS static random access memory organized as 131,072 words by 8 bits. It is fabricated using high performance, high reliability CMOS technology.

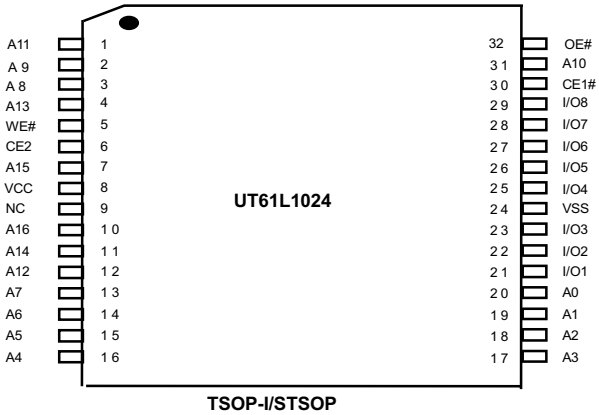
The UT61L1024 is designed for high-speed system applications. It is particularly suited for use in high-density high-speed system applications.

The UT61L1024 operates from a single 3.3V power supply and all inputs and outputs are fully TTL compatible.

PIN CONFIGURATION



PDIP/SOJ



TSOP-I/STSOP

ABSOLUTE MAXIMUM RATINGS*

PARAMETER	SYMBOL	RATING	UNIT
Terminal Voltage with Respect to Vss	VTERM	-0.5 to +4.5	V
Operating Temperature	TA	0 to +70	℃
Storage Temperature	TSTG	-65 to +150	℃
Power Dissipation	P_D	1	W
DC Output Current	IOUT	50	mA
Soldering Temperature (under 10 sec)	Tsolder	260	℃

*Stress greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

TRUTH TABLE

MODE	CE1#	CE2	OE#	WE#	I/O OPERATION	SUPPLY CURRENT
Standby	H	X	X	X	High - Z	ISB,ISB1
Standby	X	L	X	X	High -Z	ISB,ISB1
Output Disable	L	H	H	H	High - Z	ICC
Read	L	H	L	H	DOUT	ICC
Write	L	H	X	L	DIN	ICC

Note: H = V_{IH}, L=V_{IL}, X = Don't care.

DC ELECTRICAL CHARACTERISTICS (VCC = 3.1～3.6V, TA = 0℃ to 70℃)

PARAMETER	SYMBOL	TEST CONDITION		MIN.	MAX.	UNIT
Input High Voltage	VIH			2.0	VCC+0.5	V
Input Low Voltage	VIL			- 0.5	0.6	V
Input Leakage Current	ILI	VSS ≦VIN ≦VCC		- 1	1	μA
Output Leakage Current	ILO	VSS ≦VI/O ≦VCC CE1# = VIH or CE2 = VIL or OE# = VIH or WE# = VIL		- 1	1	μA
Output High Voltage	VOH	IOH = - 4mA		2.4	-	V
Output Low Voltage	VOL	IOL = 8mA		-	0.4	V
Operating Power Supply Current	ICC	CE1# = VIL , CE2 = VIH II/O = 0mA , Cycle=Min.	- 12	-	100	mA
			- 15	-	90	mA
Standby Power Supply Current	ISB	CE1# = VIH or CE2 = VIL		-	20	mA
	ISB1	CE1#≧VCC-0.2V or CE2≦0.2V		-	3	mA

CAPACITANCE (TA=25℃, f=1.0MHz)

PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Input Capacitance	CIN	-	8	pF
Input/Output Capacitance	CI/O	-	10	pF

Note : These parameters are guaranteed by device characterization, but not production tested.

AC TEST CONDITIONS

Input Pulse Levels	0V to 3.0V
Input Rise and Fall Times	5ns
Input and Output Timing Reference Levels	1.5V
Output Load	C_L=30pF, I_{OH}/I_{OL}=-4mA/8mA

AC ELECTRICAL CHARACTERISTICS (VCC = 3.1～3.6V , TA = 0℃ to 70℃)

(1) READ CYCLE

PARAMETER	SYMBOL	UT61L1024-12		UT61L1024-15		UNIT
		MIN.	MAX.	MIN.	MAX.	
Read Cycle Time	t_{RC}	12	-	15	-	ns
Address Access Time	t_{AA}	-	12	-	15	ns
Chip Enable Access Time	t_{ACE1}, t_{ACE1}	-	12	-	15	ns
Output Enable Access Time	t_{OE}	-	6	-	7	ns
Chip Enable to Output in Low Z	t_{CLZ1*}, t_{CLZ2*}	3	-	4	-	ns
Output Enable to Output in Low Z	t_{OLZ*}	0	-	0	-	ns
Chip Disable to Output in High Z	t_{CHZ1*}, t_{CHZ2*}	-	6	-	7	ns
Output Disable to Output in High Z	t_{OHZ*}	-	6	-	7	ns
Output Hold from Address Change	t_{OH}	3	-	3	-	ns

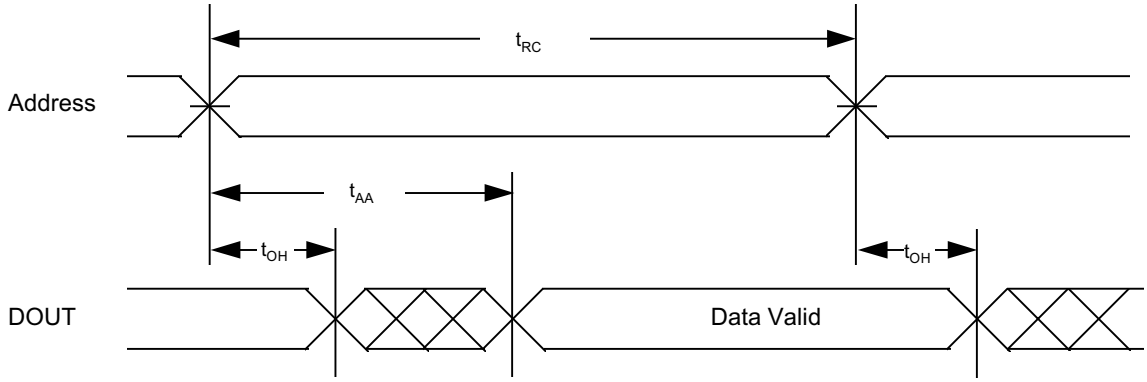
(2) WRITE CYCLE

PARAMETER	SYMBOL	UT61L1024-12		UT61L1024-15		UNIT
		MIN.	MAX.	MIN.	MAX.	
Write Cycle Time	t_{WC}	12	-	15	-	ns
Address Valid to End of Write	t_{AW}	10	-	12	-	ns
Chip Enable to End of Write	t_{CW1}, t_{CW2}	10	-	12	-	ns
Address Set-up Time	t_{AS}	0	-	0	-	ns
Write Pulse Width	t_{WP}	9	-	10	-	ns
Write Recovery Time	t_{WR}	0	-	0	-	ns
Data to Write Time Overlap	t_{DW}	7	-	8	-	ns
Data Hold from End of Write Time	t_{DH}	0	-	0	-	ns
Output Active from End of Write	t_{OW*}	3	-	4	-	ns
Write to Output in High Z	t_{WHZ*}	-	7	-	8	ns

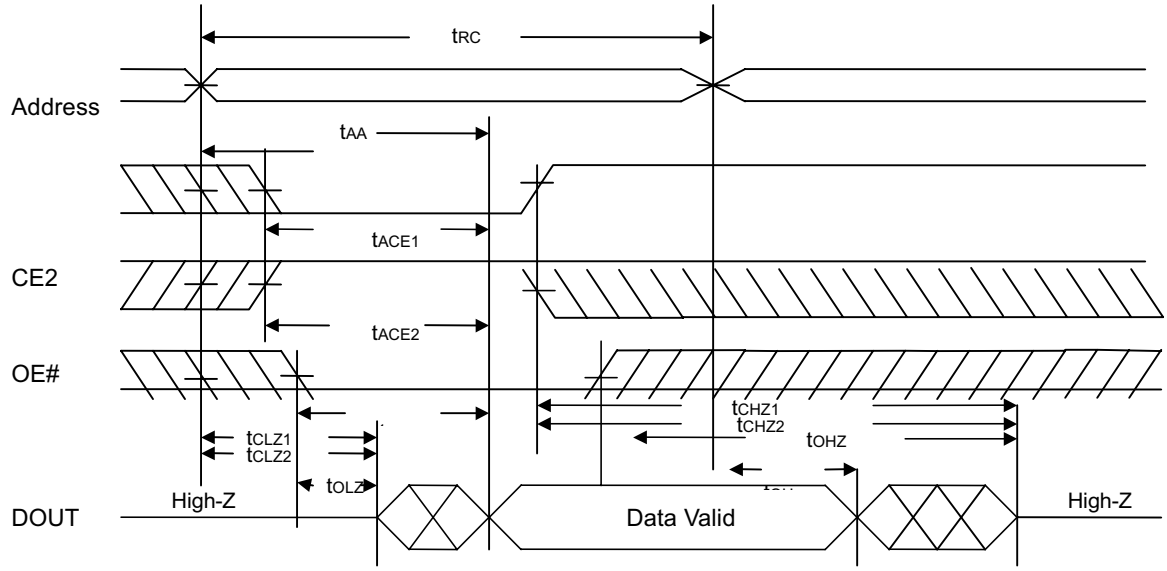
*These parameters are guaranteed by device characterization, but not production tested.

TIMING WAVEFORMS

READ CYCLE 1 (Address Controlled) (1,2,4)

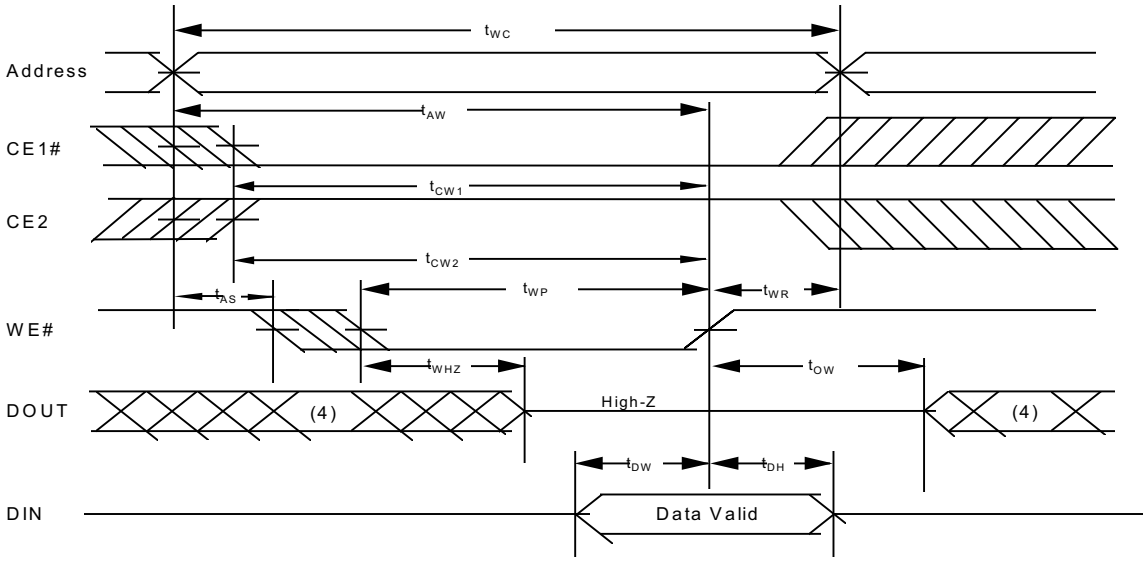


READ CYCLE 2 (CE#, CE2 and OE# Controlled) (1,3,5,6)

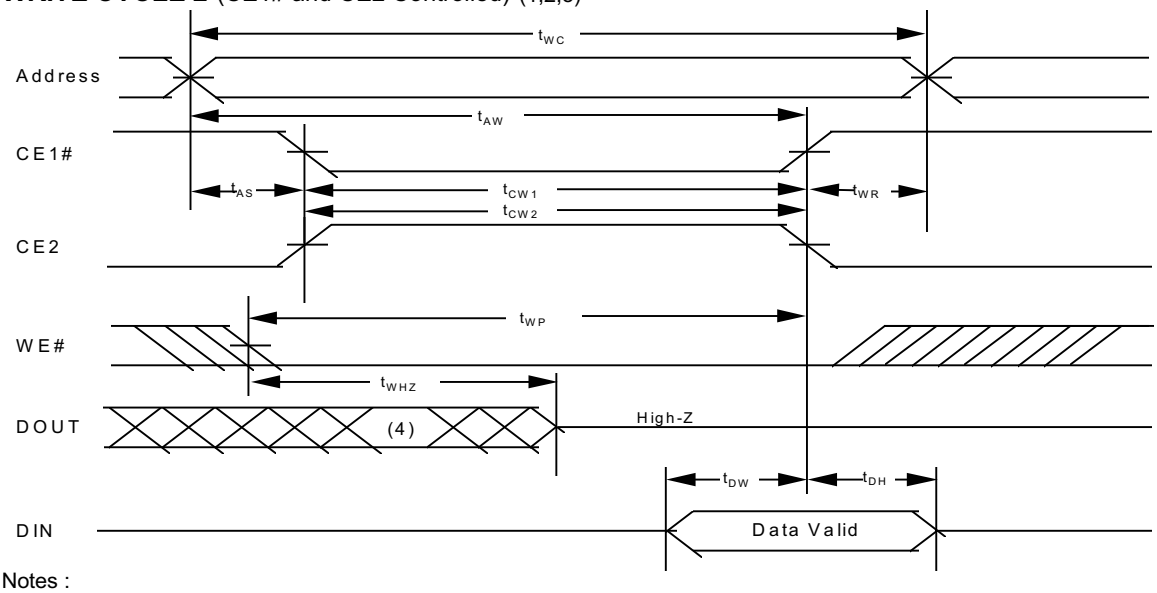


Notes :
1. WE# is HIGH for read cycle.
2. Device is continuously selected CE1#=V_{IL} and CE2=V_{IH}.
3. Address must be valid prior to or coincident with CE1# and CE2 transition; otherwise t_{AA} is the limiting parameter.
4. OE# is low.
5. t_{CLZ1}, t_{CLZ2}, t_{OLZ}, t_{CHZ1}, t_{CHZ2} and t_{OHZ} are specified with C_L=5pF. Transition is measured ±500mV from steady state.
6. At any given temperature and voltage condition, t_{CHZ1} is less than t_{CLZ1}, t_{CHZ2} is less than t_{CLZ2}, t_{OHZ} is less than t_{OLZ}.

WRITE CYCLE 1 (WE# Controlled) (1,2,3,5)



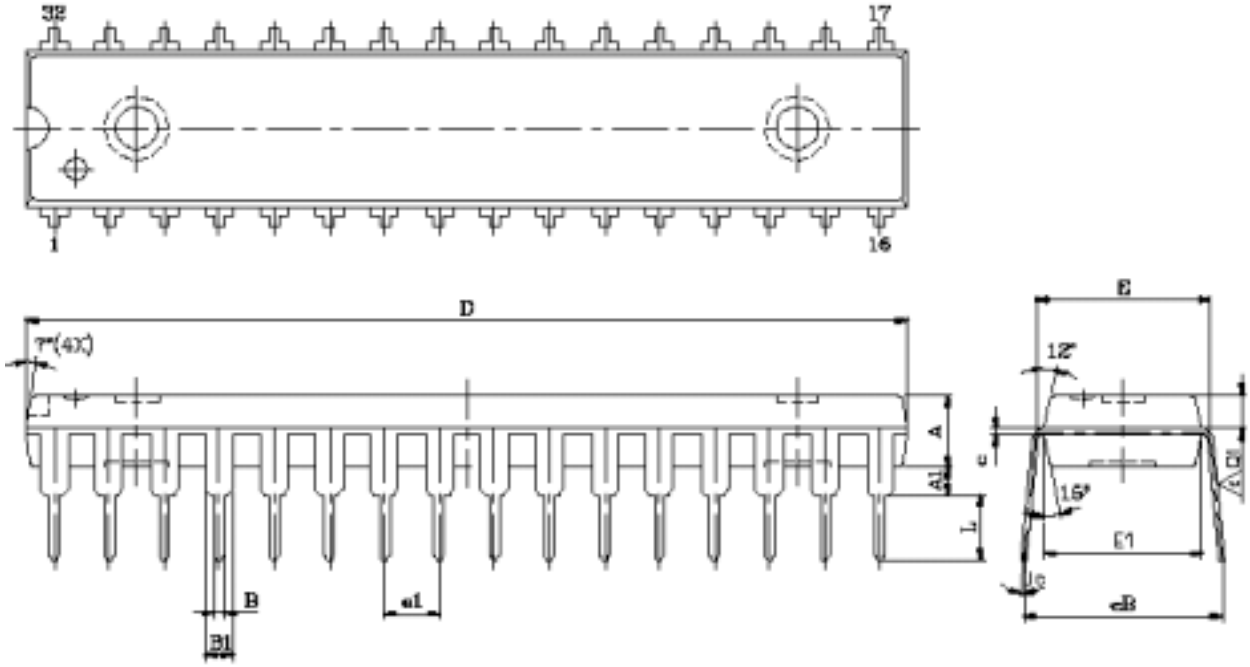
WRITE CYCLE 2 (CE1# and CE2 Controlled) (1,2,5)



Notes :
1. WE# or CE# must be HIGH during all address transitions.
2. A write occurs during the overlap of a low CE# and a low WE#.
3. During a WE# controlled with write cycle with OE# LOW, t_{WP} must be greater than $t_{WHZ}+t_{DW}$ to allow the drivers to turn off and data to be placed on the bus.
4. During this period, I/O pins are in the output state, and input singals must not be applied.
5. If the CE# LOW transition occurs simultaneously with or after WE# LOW transition, the outputs remain in a high impedance state.
6. t_{OW} and t_{WHZ} are specified with C_L = 5pF. Transition is measured ±500mV from steady state.

PACKAGE OUTLINE DIMENSION

32 PIN P-DIP (300MIL) PACKAGE OUTLINE DIMENSION



SYMBOL \ UNIT	INCH(BASE)	MM(REF)
A	0.130 ±0.005	3.302 ±0.127
A1	0.015(MIN)	0.381 (MIN)
B	0.018 ±0.004	0.457 ±0.102
B1	0.050 ±0.008	1.270 ±0.203
c	0.010 ±0.004	0.254 ±0.102
D	1.600 ±0.005	40.640 ±0.127
E	0.315 ±0.010	8.001 ±0.254
E1	0.288 ±0.004	7.315 ±0.102
e1	0.100 TYP	2.540 TYP
eB	0.350 ±0.020	8.890 ±0.508
L	0.125 (MIN)	3.175 (MIN)
△C Q1	0.060 ±0.005	1.524 ±0.127
⌞c	0°～10°	0°～10°

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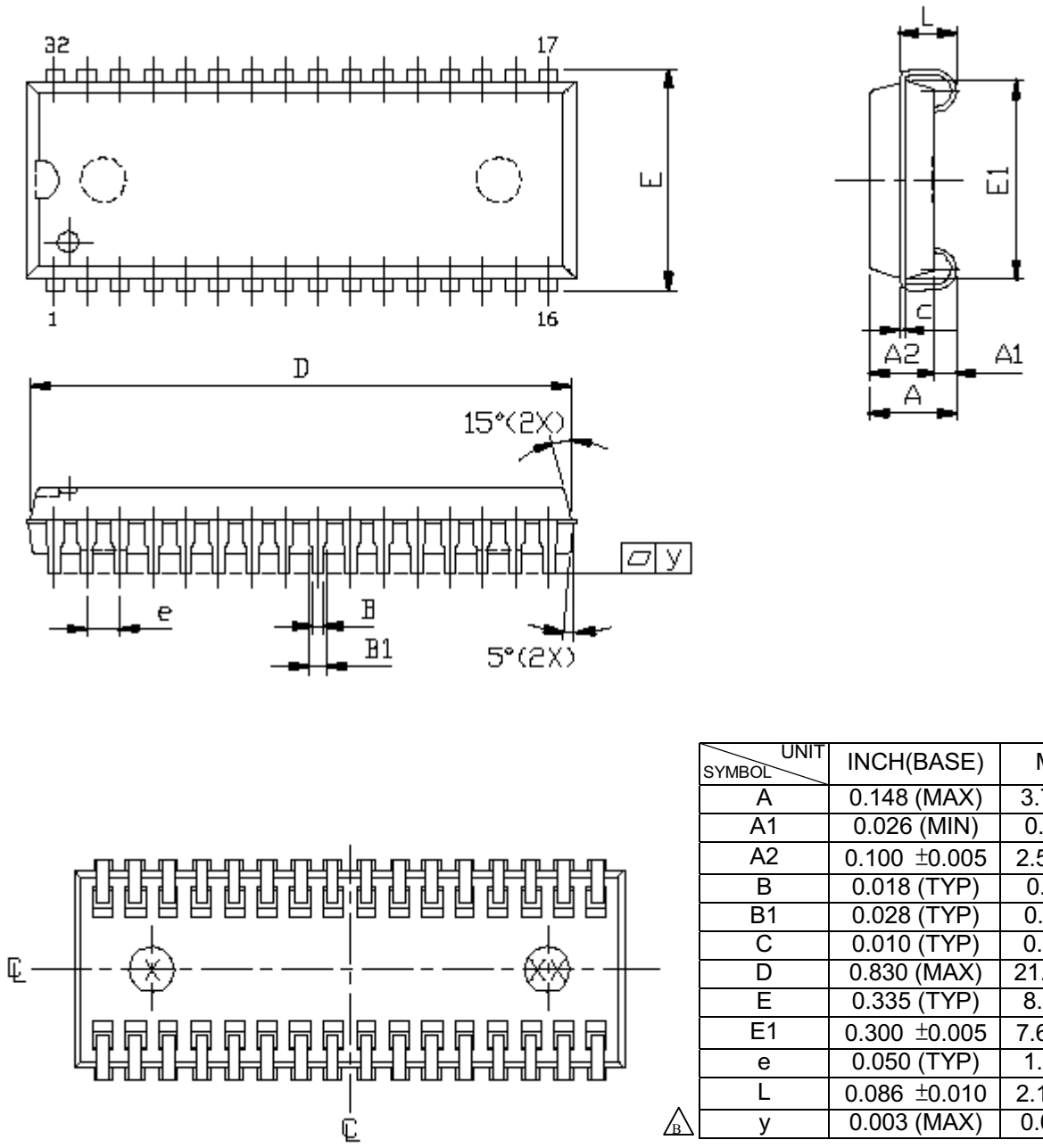
1F, No. 11, R&D Rd. II, Science-Based Industrial Park, Hsinchu, Taiwan, R. O. C.
TEL: 886-3-5777882 FAX: 886-3-5777919

32PIN SOJ PACKAGE OUTLINE DIMENSION



SYMBOL \ UNIT	INCH(BASE)	MM(REF)
A	0.148 (MAX)	3.759 (MAX)
A1	0.026 (MIN)	0.660 (MIN)
A2	0.100 ±0.005	2.540 ±0.127
B	0.018 (TYP)	0.457(TYP)
B1	0.028 (TYP)	0.711 (TYP)
C	0.010 (TYP)	0.254 (TYP)
D	0.830 (MAX)	21.082 (MAX)
E	0.335 (TYP)	8.509 (TYP)
E1	0.300 ±0.005	7.620 ±0.127
e	0.050 (TYP)	1.270 (TYP)
L	0.086 ±0.010	2.184 ±0.254
y	0.003 (MAX)	0.076 (MAX)

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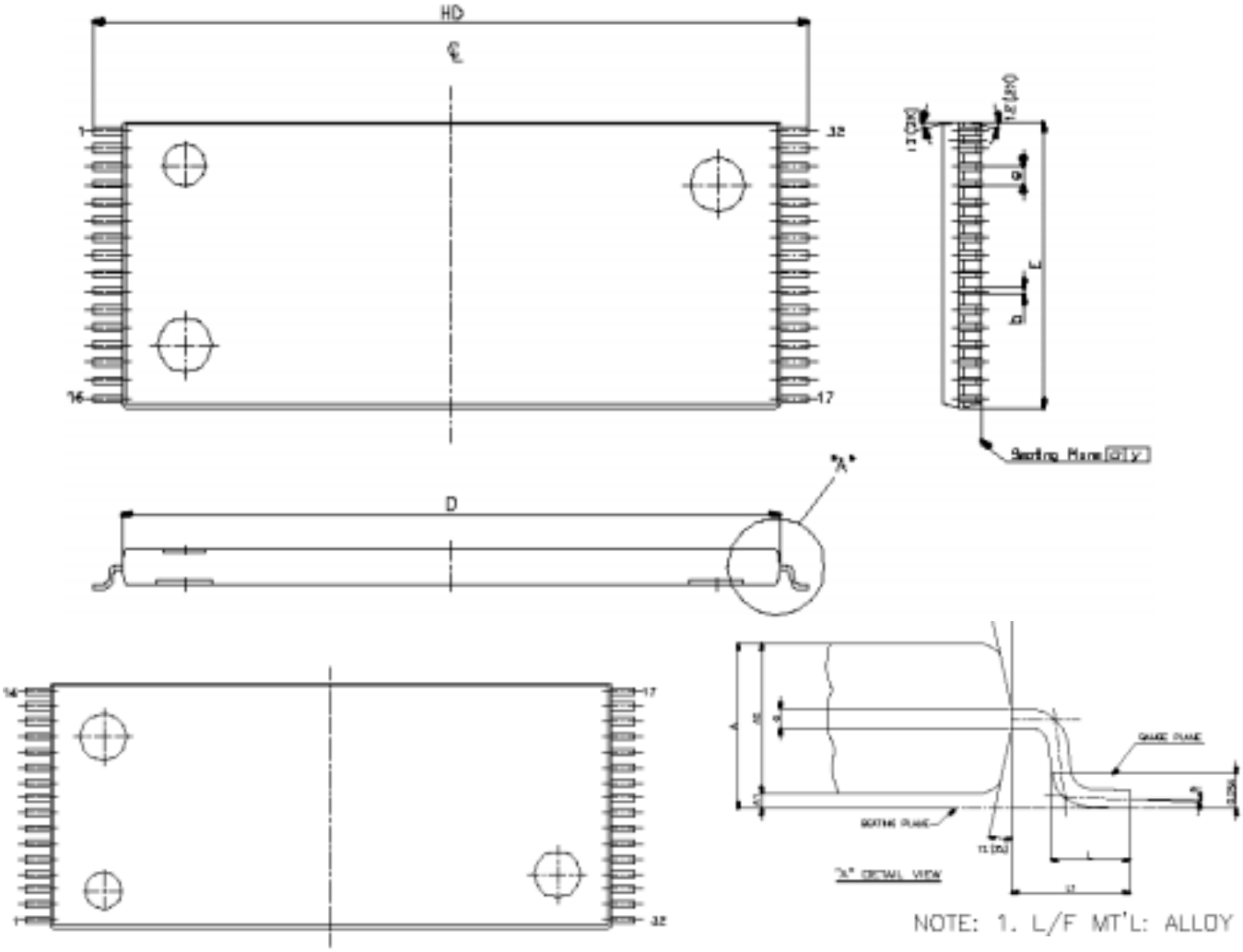
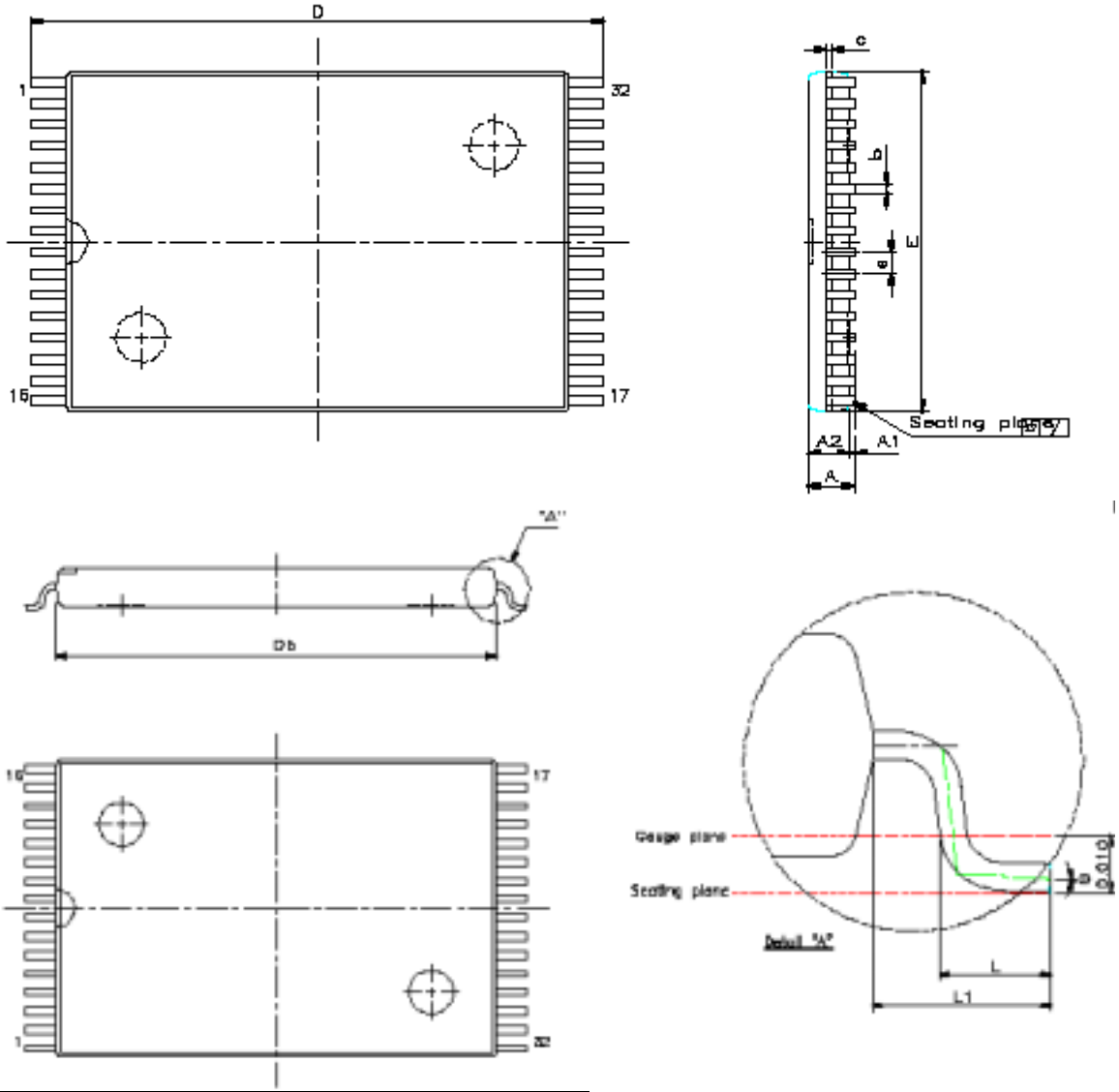
32PIN TSOP-I PACKAGE OUTLINE DIMENSION



SYMBOL \ UNIT	INCH(BASE)	MM(REF)
A	0.047 (MAX)	1.20 (MAX)
A1	0.004 ±0.002	0.10 ±0.05
A2	0.039 ±0.002	1.00 ±0.05
b	0.008 + 0.002 - 0.001	0.20 + 0.05 -0.03
c	0.005 (TYP)	0.127 (TYP)
D	0.724 ±0.004	18.40 ±0.10
E	0.315 ±0.004	8.00 ±0.10
e	0.020 (TYP)	0.50 (TYP)
HD	0.787 ±0.008	20.00 ±0.20
L	0.0197 ±0.004	0.50 ±0.10
L1	0.0315 ±0.004	0.08 ±0.10
y	0.003 (MAX)	0.076 (MAX)
θ	0°～5°	0°～5°

32 pin 8mm x 13.4mm STSOP PACKAGE OUTLINE DIMENSION



UNIT / SYMBOL	INCH(BASE)	MM(REF)
A	1.20(Max.)	0.047(Max).
A1	0.10±0.05	0.004±0.002
A2	1.00±0.05	0.039±0.002
b	020(typ.)	0.006(typ.)
c	0.15(typ.)	0.006(typ.)
D	13.40±0.20	0.526±0.006
Db	11.80±0.10	0.465±0.004
E	8.000±0.10	0.315±0.004
e	0.50(typ.)	0.020(typ.)
L	0.50±0.10	0.020±0.004
L1	0.80±0.10	0.0315±0.004
y	0.08(Max.)	0.003(Max.)
e	0°~5°	0°~5°

Note：
E dinmension is not including end flash.
The total of both sides' end flash Is not above 0.3mm.

UTRON TECHNOLOGY INC. June 14, 2000
1F, No. 11, R&D Rd. II, Science-Based Industrial Park, Hsinchu, Taiwan, R. O. C.
TEL: 886-3-5777882 FAX: 886-3-5777919

ORDERING INFORMATION

PART NO.	ACCESS TIME (ns)	PACKAGE
UT61L1024KC-12	12	32PIN SKINNY PDIP
UT61L1024KC-15	15	32PIN SKINNY PDIP
UT61L1024JC-12	12	32PIN SOJ
UT61L1024JC-15	15	32PIN SOJ
UT61L1024LC-12	12	32PIN TSOP-1
UT61L1024LC-15	15	32PIN TSOP-1